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IC-SPECIFICATION

TUA 4300 G

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ONE CHIP CAR RADIO

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This specification replaces the previous editions

DOK-Nr.	date	DOK-Nr.	date

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Functional Description, Application

General Description

The TUA 4300 G is a one chip car radio system consisting of AM/FM receiver, AM-Up/Down conversion, AGC amplifier / demodulator, FM-IF limiter amplifier / demodulator and stereodecoder / noiseblanker.

1. AM/FM-Receiver

The TUA 4300 G is an integrated combined AM-FM-receiver with strictly symmetrical RF parts for use in car radios.

Features

- High flexibility with an external preamplifier stage for AM and FM
- Strictly symmetrical RF parts
- Separate mixers for AM and FM mode
- Sym. or asym. mixer inputs
- Only one 2-pin-oscillator for the 1st LO (in AM mode the oscillator frequency is divided by 8 or 10)
- 1st LO with LC-tank circuit
- 1st LO at 100 MHz range
- 1st LO decoupled counter output
- 1st LO decoupled divided counter output
- Low phase noise
- FM/AM field strength output combined

2. FM Mode

A. FM-Receiver

In this mode, the receiverpart is comprised of a mixer, an oscillator, a prestage control and an IF post amplification.

Features

- Integrated AGC generation for PIN Diodes and MOSFETs
- High level mixer input
- High input/output 3.order interceptpoint

B. FM-IF Demodulator

The FM-IF-demodulator has been developed especially for car radio applications.

Features

- 7stage limiter amplifier
- Coincidence demodulator
- Field strength output (combined with AM)
- Fixed mute depth (with full muting typ 80dB)
- Multipath detector with analog output

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Functional Description, Application

3. Stereodecoder

This part provides the stereo decoder function and noise blanking for FM car radio applications.

Features

- Internal reference voltage source
- Adjustment free oscillator with ceramic resonator 456 kHz
- Pilot dependent mono/stereo switching with hysteresis
- Stereo indicator output
- Analog mono/stereo blend control (stereo noise control, SNC)
- Pilot canceller (19 kHz)
- Adjacent channel noise suppression (114 kHz)
- Mute facility
- Analog deemphasis control (high cut control, HCC)
- Interference noise detector with integrated high-pass filter (IF level signal or MPX input)
- MPX-input low-pass filter
- Noise blanking at MPX -demodulator outputs.
- L, R audio is common to AM.

4. AM Mode

In this mode, the IC is comprised of a mixer, an oscillator with a divider by 8 or 10, a prestage control, an IF post amplification, 2nd mixer with AGC to convert the 1st IF to the 2nd IF, 2nd local oscillator (buffer for external source), automatic gain controlled amplifier and quasisynchronous demodulator.

The same oscillator is used in AM and FM mode.

Features

- 2nd mixer with AGC
- 1st IF amp; use of CER filter or crystal filter possible
- 2nd LO with quartz or external source
- Output for AM IF counter
- Wide range 2nd IF AGC amplifier
- Quasi synchronous demodulator for AM mode
- Fast AM search tuning stop feature
- HCC for AM

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Circuit Description

1. AM/FM-Receiver

The AM/FM-receiver part includes a 2-pin varactor tuned oscillator. In the FM mode the direct oscillator frequency is fed into the double balanced FM mixer, in the AM mode the divided by 8 or 10 oscillator frequency is fed into the AM mixer.

The two separate symmetrical input stages of the IC, one optimized for FM-, the other for AM- mode allow symmetrical and unsymmetrical prestage configuration.

The AM and FM input frequencies are converted to a fix 1st IF in the 10.7 MHz range. The IF is post amplified in separate IF amplifiers, one optimized for FM, the other for AM. Using of a CER filter or crystal filter is possible.

The TUA 4300 G has been designed to work with a PLL in the 100MHz range in both modes or in the AM- mode with the divided frequency.

Depending on the input signal strength, the integrated AGC stage for prestage control drives PIN-Diodes as well as MOSFETs.

2. FM-MODE

A. FM-IF Demodulator

The FM-IF amplifier includes a 7 stage capacitive coupled limiter amplifier with coincidence demodulator and AF output. The AF output signal can be continuously attenuated to decrease the noise.

There is a field strength output (with min. 76 dB dynamic range, typ. ±1 dB nonlinearity and typ. ±3 dB temperature drift) and a fixed muting (with full muting typ 80 dB).

A multipath detector with analog output is available. Its input signal is fed from the high pass filter of the stereo-decoder/noiseblanker and a second 80 kHz 1-pole high pass filter.

3. Stereodecoder

Power supply, reference current:

A temperature-stable, low noise reference voltage generator is used for better ripple rejection and to generate a reference current. This current is used as a time base for the deemphasis, the gate time of the pulse former, and the pilot cancellation, avoiding temperature and tolerance effects .

MPX input, MPX filter:

A 4-pole low-pass filter determines the bandwidth of the MPX signal.

Voltage Controlled Oscillator, Phase Detector:

The 456 kHz oscillator and the frequency dividers are used as walsh function generators (suppression of 3rd

order harmonics) for: 38 kHz for the stereo decoder

19 kHz inphase for phase detector and pilot cancellation

19 kHz quadrature for the phase detector.

The phase detector locks the on chip 19 kHz signal to the pilot tone in the MPX signal at 90 deg phase.

Pilot Detector, Pilot Indicator, Pilot Cancellation:

The voltage at the pilot detector output is proportional to the pilot tone input level. If that level is high enough, the pilot indicator output is activated and the pilot cancellation turned on: a 19 kHz signal proportional to the voltage at the pilot detector output is added to the MPX signal with inverse polarity, cancelling the 19 kHz pilot tone.

Interference Detector, Noise Detector, Pulse Former:

The signal from the interference input (MPX or field strength signal) passes a 4-pole high-pass filter to the noise blanking circuitry. The average noise level is stored in an external capacitor. The interference detector compares the actual noise level with that stored in the capacitor and triggers the pulse former if there is a significant difference. The pulse former generates a gate pulse for the HCC block. During that pulse time the outputs of the deemphasis circuit are switched to hold mode.

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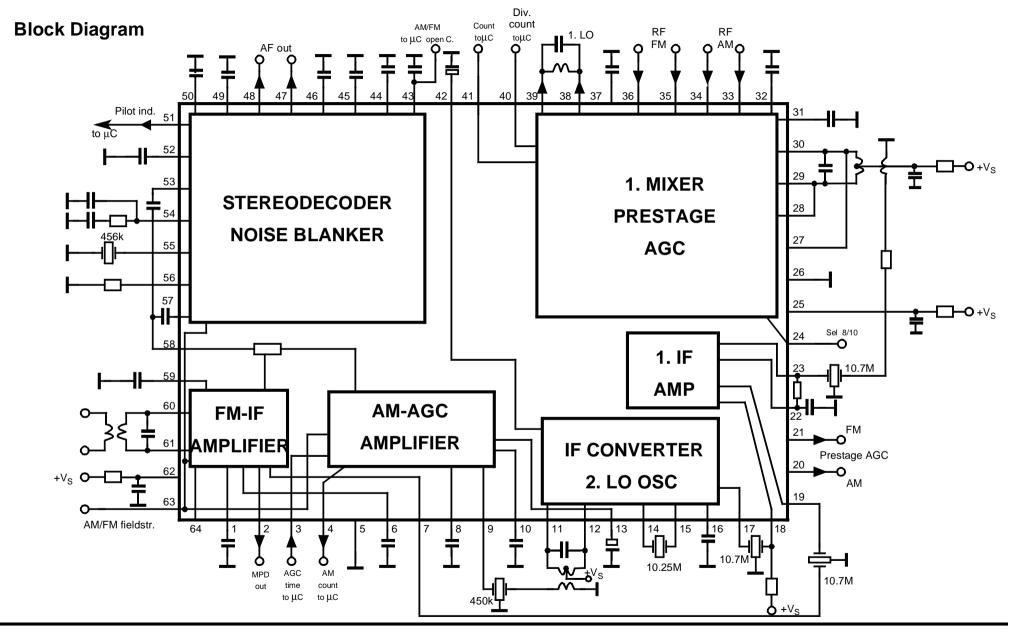
TUA 4300 G

Circuit Description

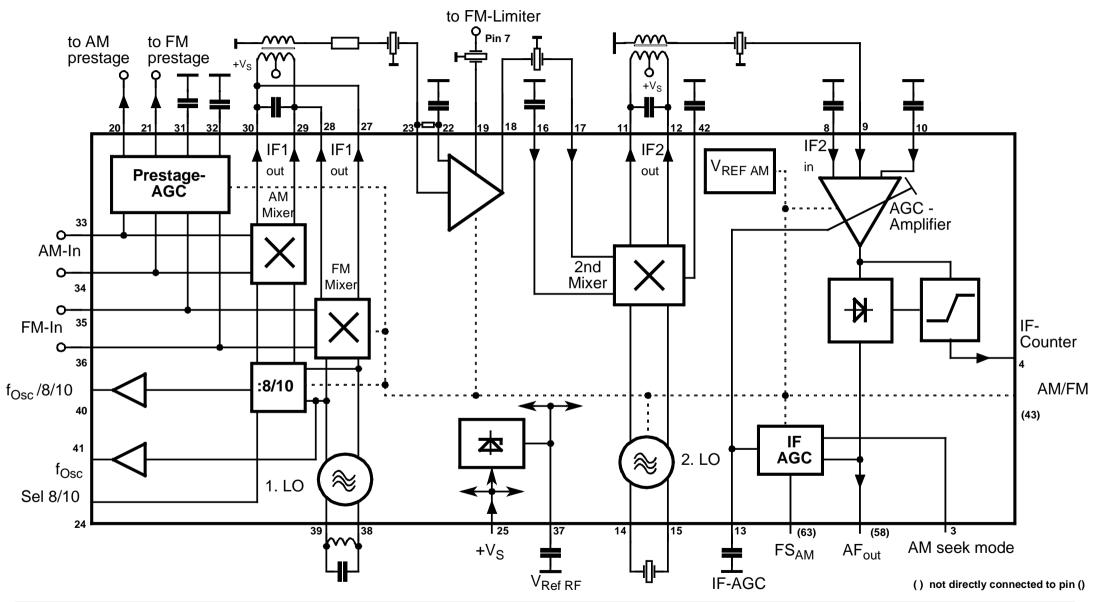
3. AM - MODE

In the AM mode the 1st IF is converted by the 2nd mixer into the 2nd IF in the 450 kHz range. Therefore a 2nd LO, which is used with quartz or as input for external sources, is part of the IC. An AGC in this mixer increases sensitivity. The 2nd IF signal passes an automatic gain controlled IF amplifier and is then demodulated to the AF in a quasisynchronous demodulator. Switching to seek mode, the AGC time constant is reduced by a factor of 5, the 2nd mixer AGC is forced to high gain, the AM IF counter output is switched on and the AF is muted. The AGC voltage is used as AM field strength and is fed to the combined field strength output.

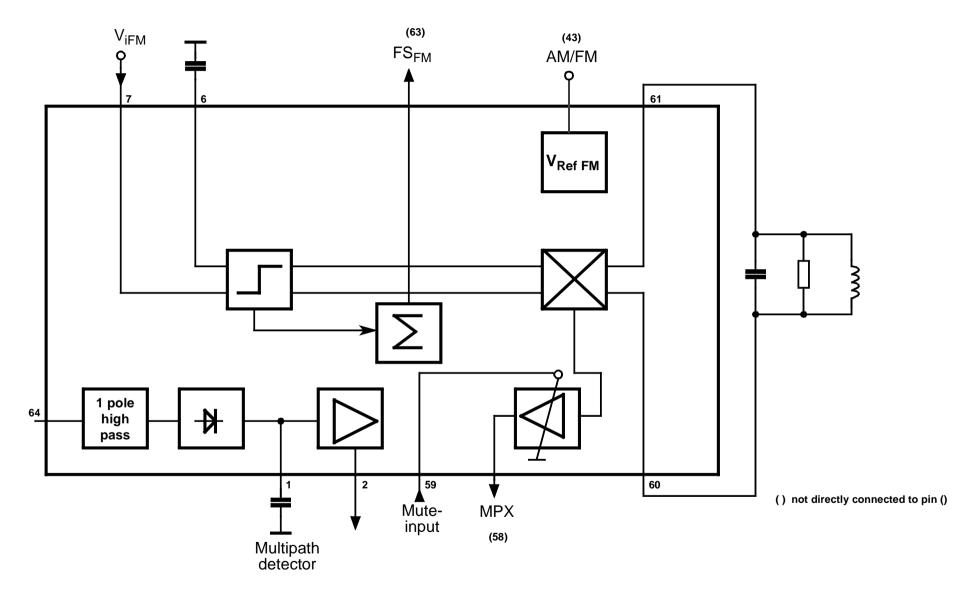
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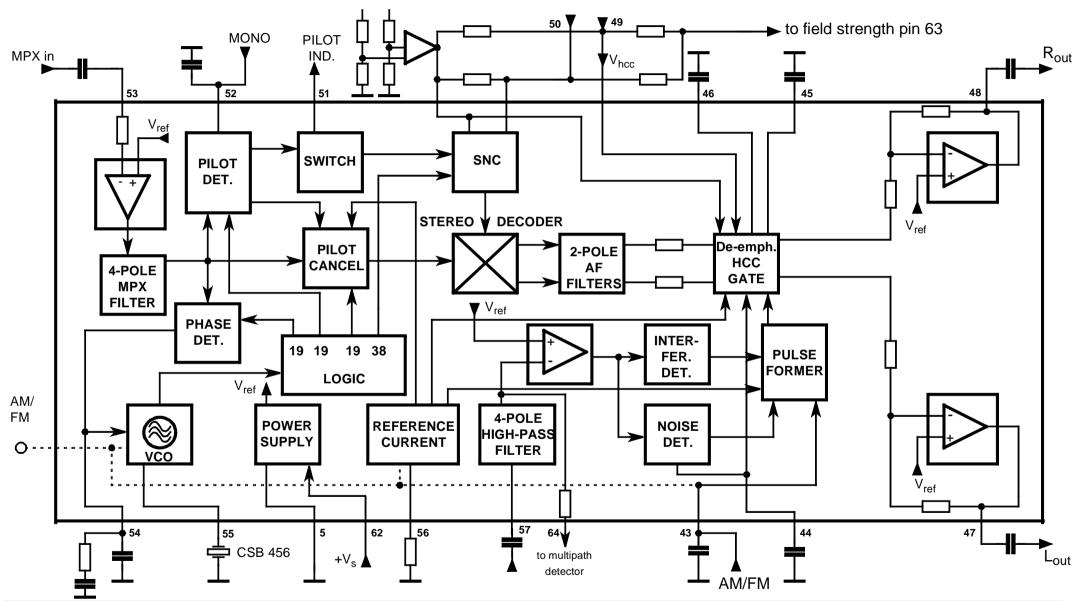
Block Diagram AM/FM Receiver



Block Diagram FM-IF Amplifier



Block Diagram Stereodecoder/Noiseblanker



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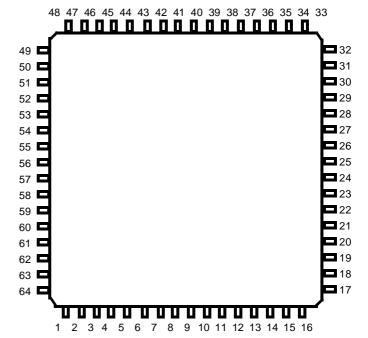
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Pin Assignment

- 1 Multipath det. cap.
- 2 Multipath det. output
- 3 AM seek mode switch
- 4 AM-IF-counter out
- 5 GND_{IF}
- 6 FM-IF input
- 7 FM-IF input
- 8 AM-IF bias
- 9 AM-IF input
- 10 AM-IF bias
- 11 2nd mixer out
- 12 2nd mixer out
- 13 AM IF AGC cap.
- 14 2nd LO quartz
- 15 2nd LO quartz
- 16 2nd mixer input
- 17 2nd mixer input
- 18 IF amp out AM
- 19 IF amp out FM
- 20 V_{Prestage} AGC AM
- 21 I_{Prestage} AGC FM
- 22 IF amp input bias
- 23 AM IF amp input
- 24 SEL 8 / 10
- 25 +V_{S RF}
- 26 GND_{RF}
- 27 FM mixer output
- 28 FM mixer output
- 29 AM mixer output
- 30 AM mixer output
- 31 Prestage AGC cap. AM
- 32 Prestage AGC cap. FM
- 33 RF input AM
- 34 RF input AM
- 35 RF input FM
- 36 RF input FM
- 37 V_{REF RF}
- 38 RF oscillator
- 39 RF oscillator
- 40 Divided counter out
- 41 Direct counter out
- 42 2nd mixer AGC cap.
- 43 Noise gate cap./AM-FM
- 44 Noise level cap.
- 45 Deemphasis right
- 46 Deemphasis left
- 47 AF output left
- 48 AF output right
- 49 Control voltage HCC



- 50 Control voltage SNC
- 51 Pilot indicator output
- 52 Pilot detector cap.
- 53 MPX-signal input
- 54 Stereo PLL
- 55 Stereo oscillator
- 56 I_{ref stereo}
- 57 Noise detector input
- 58 MPX-signal output
- 59 Mute FM
- 60 Demodulator circuit FM
- 61 Demodulator circuit FM
- 62 +V_{S IF}
- 63 Fieldstrength output
- 64 Multipath det. input

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33)

AM 1st mixer symmetrical inputs

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Pin Description

1)	Multipath detector rectifier capacitor
2)	Analog multipath detector output
3)	AM seek mode switch; AM IF counter on, 2nd mixer gain high,
	AM-AGC fast and AM AF mute
4)	AM-IF counter output for search tuning
5)	Ground IF and stereodecoder section
6)	FM limiter input bias decoupling capacitor
7)	FM limiter input
8)	AM AGC amplifier bias decoupling capacitor
9)	AM AGC amplifier input
10)	AM AGC amplifier bias decoupling capacitor
11)	2nd AM mixer outputs (open collector)
12)	2nd AM mixer outputs (open collector)
13)	AM AGC amplifier time constant capacitor
14)	Oscillator input for 2nd AM mixer
15)	Oscillator input for 2nd AM mixer
16)	2nd AM mixer bias decoupling capacitor
17)	2nd AM mixer input
18)	10.7 MHz IF amplifier output AM (open collector)
19)	10.7 MHz IFamplifier output FM
20)	AM prestage AGC buffered voltage output with fast attack, slow decay feature
21)	FM prestage AGC current output for PIN diode
22)	10.7 MHz IF amplifier operation point
23)	10.7 MHz IF amplifier input AM
24)	AM 1st local oscillator divider control for dividing by 10 for long wave and
	medium wave receiving or dividing by 8 for short wave receiving
25)	Supply voltage RF section
26)	Ground RF section
27)	FM mixer outputs (open collector)
28)	FM mixer outputs (open collector)
29)	AM mixer outputs (open collector)
30)	AM mixer outputs (open collector)
31)	AM prestage AGC time constant capacitor
32)	FM prestage AGC time constant capacitor; output for MOS FET Gate 2

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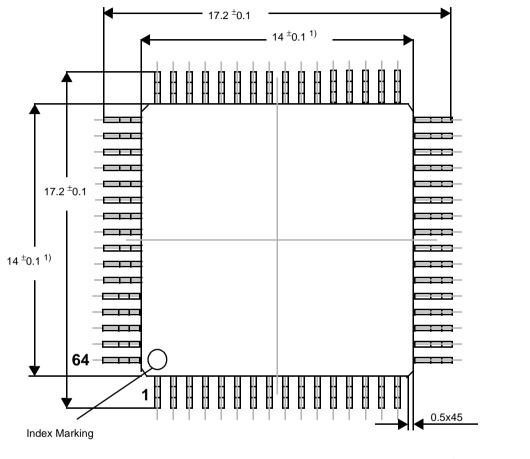
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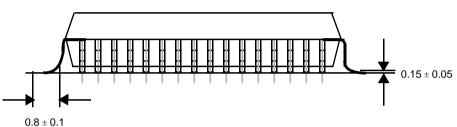
Pin Description

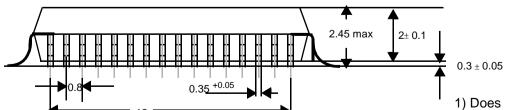
34)	AM 1st mixer symmetrical inputs
35)	FM 1st mixer symmetrical inputs
36)	FM 1st mixer symmetrical inputs
37)	Reference voltage RF section (4.8 V)
38)	1st local AM/FM oscillator circuit
39)	1st local AM/FM oscillator circuit
40)	1st local oscillator divided by 8/10 counter output (disabled in FM mode)
41)	1st local oscillator counter output
42)	2nd AM mixer AGC time constant capacitor
43)	Timing capacitor for Noisedetector monoflop (gate time)
	AM/FM mode control; low voltage activates AM section
	and disables stereodecoder VCO, Phase detector, Pilot detector, SNC and FM section
44)	Hold capacitor for Noise detector average level
	low voltage applied mutes the stereo decoder outputs
45)	HCC timing / hold capacitor, deemphasis right
46)	HCC timing / hold capacitor, deemphasis left
47)	AF output left
48)	AF output right
49)	Control voltage HCC (high cut control)
50)	Control voltage SNC (stereo noise control)
51)	Pilot indicator output, active high (open collector)
52)	Pilot detector capacitor, low voltage activates mono state
53)	Stereo decoder MPX signal input
54)	Stereo decoder PLL phasedetector, loop filter
55)	VCO pin for ceramic resonator
56)	Reference current pin, external reference resistor
57)	Noise detector input
58)	FM MPX signal and AM demodulator signal output
59)	Dynamic FM mute control blocking capacitor
60)	Demodulator circuit FM
61)	Demodulator circuit FM
62)	Supply voltage IF and stereodecoder section
63)	AM/FM fieldstrength combined output
64)	Auxiliary multipath detector input (in parallel to internal connection)

Package Outline



Plastic-Package P-MQFP-64





1) Does not include plastic or metal protrusions of 0.25max per side

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Absolute Maximum Ratings

The maximal ratings may not be exceeded under any circumstances, not even momentarily and individually, as permanent damage to the IC will result.

#	Max. Ratings for ambient temperature T _{amb}	Symbol	Min	Max	Units	Remarks
-40 °C	to 85 °C					
1	Junction temperature	T_J	-40	150	°C	
2	Storage temperature	T_S	-40	125	°C	
3	Thermal resistance	R_{thSA}		54	K/W	
4	ESD-voltage, HBM	V_{ESD}	-4	+4	kV *)	100pF, 1500 Ω
	3.4137.50B					

^{*) 4} kV ESD protection is not valid for pin 14, 15 and 37.

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Operational Range

Within the operational range the IC operates as described in the circuit description. The AC / DC characteristic limits are not guaranteed.

#	Parameter	Symbol	Min	Max	Units	Remarks
1	Supply voltage	V_S	8	9	V	
2	Ambient temperature	T_A	-40	85	°C	

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AC/DC Characteristics

AC / DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature range. Typical characteristics are the median of the production.

#	Parameter	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units			
	Supply voltage V_S =8.5 V Ambient temperature T_{amb} = 25 $^{\circ}C$										
1	Current consumption	I _{SFM}	FM mode	1	80	100	120	mA			
<u>1.AN</u>	M/FM-Receiver	I _{SAM}	AM mode	1	76	95	114	mA			
<u>1st l</u>	<u>o</u>										
	Frequency range	f _{1st LO}	0	1 Lab	80 50		140 150	MHz MHz			
	Frequency range Counter output	f _{1st LO} V ₄₁	$Q_{factor\ of\ coil} > 90$ $R_{L41} = 330\Omega$	Lab 1	100	130	130	mV _{rms}			
	Divided counter output	t V ₄₀	$R_{L40} = 330\Omega$	1	100	130		mV _{rms}			
	Output impedance	R ₄₀	240	Lab	8.0	1	1.2	$k\Omega$			
	Output impedance	R ₄₁		Lab	240	300	360	Ω			
	Frequency	f _{1st LO}	$V_{\text{tuning}}=0V$		tbf			MHz			
	MHz IF amplifier DC input voltage	V	f _{IF1} = 10.7 MHz	4	4.4	4.7	F 0	V			
	Input resistance	V ₂₃ R ₂₃	AM/FM	1 1	4.4 1.5	4.7 1.8	5.0 2.2	v kΩ			
	Output resistance	R ₁₈	open Collector	1	100	1.0	2.2	kΩ			
11		R ₁₉	open concere.	1	265	330	396	Ω			
12	Voltage gain	A ₂₃₋₁₉	FM, R ₁₉ =330Ω	Lab	24	27	30	dB			
13	Voltage gain	A ₂₃₋₁₈	AM, R ₁₈ =165Ω	Lab	8	11	14	dB			
	Noise figure	F_{AM}	RG=330Ω	Lab		6		dB			
	Noise figure	F _{FM}	RG=330Ω	Lab		7		dB			
	Reference voltage	V ₃₇		1	4.5	4.8	5.1	V			
17	Output Current	l ₃₇		1			1	mA			
AM	<u>mode</u>		f_{IF1} = 10.7 MHz f_{IF2} = 450 kHz f_{33-34} = 1 MHz V_{43} =1V								
Mixe											
1	Interceptpoint	I _{P3}	Consider the state of the state	Lab		134		dΒμV			
2	3rd order Mixer gain	A _{M1}	Special testcircuit necessary V _{33,34} =80mV _{rms} ;V _{out} =V ₂₃ (X _F =1k5//5p;a _F =-2dB)	Lab		-2		dB			
3	Over all gain	A_{MIF}	V _{33,34} =80mV _{rms} ; V _{out} =V _{IF10}	.7 1	1	5	9	dB			
4	Max. input voltage	V ₃₃₋₃₄	SINAD> 34dB;m=80%	1	1100	1400		mV_pp			
5	Noise figure (10 MHz)	F	$R_{g \text{ opt}} = 700\Omega$	Lab		7		dB			
6	Input impedance	R ₃₃₋₃₄	sym.	Lab	3.2	4	4.8	kΩ			
7		C ₃₃₋₃₄	sym.	Lab	1.6	2	2.4	pF			
8	Input impedance	R_{33-34}	asym.	Lab	1.6	2	2.4	kΩ			
9	Input impedance	C_{33-34}	asym.	Lab	3.2	4	4.8	pF			
	1st LO divided by 8	V _{24Low}		1	0		0.7	V			
11	1st LO divided by 10	V _{24High}	or open	1	2.4		5	V			

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AC/DC Characteristics

AC / DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature range. Typical characteristics are the median of the production.

#	Parameter	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
10 11 12 13 14	tage AGC output AGC-voltage AM AGC-voltage FM AGC-current FM Integrator Current Integrator Current	V ₂₀ V ₂₀ V ₃₂ I ₂₁ I _{31*} I _{31*}	$V_{33,34} = 50 \text{mVrms} \\ V_{33,34} = 200 \text{mVrms} \\ V_{33,34} = 50 \text{mVrms} \\ V_{33,34} = 50 \text{mVrms} \\ V_{33,34} = 50 \text{mVrms} \text{Vm=3V} \\ V_{33,34} = 200 \text{mVrms} \\ V_{33,34} = 200 $	1 1 1 1 1	6 0 0 0 -30 +32	7 - 38 +40	0.5 0.15 0.1 -49 +51	V V V mA μA μA
	AM IF section							
Mixe 1	Max. Mixer gain	A _{M2}	V ₁₇ =1mV; V _{out} =V _{IF450} ₇ =10.7 MHz; f ₁₄ =10.25 MHz	1	17	20	23	dB
3 4 5 6	Mixer AGC-range Mixer gain seek mode Noise figure Integrator Current Integrator Current	ΔΑ	$\Delta A = A_{V17=1mV} - A_{V17=100 mV}$ $V_{17}=1mV; V_{3}=0.7V$ $V_{17}=0 V_{m}=3V$ $V_{17}=100mV_{rms} V_{m}=3V$	1 1 Lab 1 1	17 17 +80 - 190	20 20 10 +150 - 270	23 23 +230 - 380	dB dB dB μΑ μΑ
8 9 10	Operational frequency External force voltage Input Imp. Crystal Osc. Crystal Resistance Spurious Harm. Cryst.	V ₁₄	Rg=600 Ω ;Ck= 100pF P_{TOTC} =50 μ W; Fundamental P_{TOTC} =50 μ W; F<30 MHz	1 1 Lab	9.25 30 -500	10.25 -600	11.25 -400 100	$\begin{array}{l} \text{MHz} \\ \text{mV}_{\text{rms}} \\ \Omega \\ \Omega \\ \text{dB} \end{array}$
FM n	node		f _{IF} =10.7 MHz f ₃₅₋₃₆ =100 MHz V ₄₃ =open					
	r 1 Interceptpoint 3rd order Noise figure (10 MHz)	I _{P3} F	special testcircuit necessary $R_{g \ opt} = 500\Omega$	Lab Lab		125 6		dB μV dB
	Mixer gain	A_{M1}	$V_{35-36} = 10 \text{mV}_{\text{rms}}; V_{\text{out}} = V_{23}$	Lab		9		dB
5 6 7 8	Over all gain Input impedance Input impedance Input impedance Input impedance	A _{M IF} R ₃₅₋₃₆ C ₃₅₋₃₆ R ₃₅₋₃₆ C ₃₅₋₃₆	$ \begin{array}{l} (R_{\text{F}}\text{=}330\Omega\;;a_{\text{F}}\text{=-4dB}) \\ V_{35,36}\text{=}10\text{mV}_{\text{rms}}\;;\;V_{\text{out}}\text{=}V_{\text{IF}10}\;\\ \text{sym.}\\ \text{sym.}\\ \text{asym.}\\ \text{asym.} \end{array} $. ₇ 1 Lab Lab Lab Lab	26 3.2 1.6 1.6 3.2	32 4 2 2 4	38 4.8 2.4 2.4 4.8	dB kΩ pF kΩ pF
9 10 11 12 13	tage AGC output AGC voltage FM AGC voltage FM AGC current FM AGC current FM AGC voltage AM Integrator Current	V ₃₂ V ₃₂ I ₂₁ I ₂₁ V ₂₈ I ₃₂ *	$V_{35,36}$ =0m V_{rms} $V_{35,36}$ =50m V_{rms} $V_{35,36}$ =0 m V_{rms} $V_{35,36}$ =50m V_{rms} $V_{35,36}$ =0 V_{35} =0 V_{m} =4.8 V	1 1 1 1 1	5.6 0 9.5 0 0	6.4 12 - 25	7.2 0.1 14.5 0.1 0.5 - 46	V V mA mA V μA
15 *) Inte	Integrator Current	I ₃₂ * ured betwe	$V_{35}^{=}=100 \text{mV}_{\text{rms}}$ $V_{\text{m}}=4.8 \text{V}$ een the output pin (- Pole of the r	1 measurem	+42 ent equipr	+60	+81	μA

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AC/DC Characteristics

AC / DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature range. Typical characteristics are the median of the production.

#	Parameter	Symbol	Test	Test	Min	Тур	Max	Units
			Conditions	Circuit				

2.FM Demodulator

Measuring condition:

 f_{ilF} =10.7 MHz; Δf = ± 75 kHz; f_{mod} = 1 kHz; V_7 =10 m V_{rms}

V₄₄=open; Deemphasis= 100 μs

1	Field strength output	V ₆₃						
	-dynamic range	see Dia	gram D1	1	66	72		dB
	-nonlinearity	see Dia	gram D2	1		±1		dB
	-temperature drift	see Dia	gram D3	1			±3	dB
	-load capacitance						50	pF
	-load resistance				1			$k\Omega$
		V ₆₃	$V_7 = 200 \text{mV}_{\text{rms}}$	1	4	4.6	5.2	V
		V ₆₃	$V_7=1 \text{mV}_{\text{rms}}$	1	1.5	1.9	2.3	٧
		V ₆₃	V ₇ =0mV _{rms}	1	0		1	٧
2	AF-output voltage	V_{58FM}	R_L >10kΩ; Deemph.=100 μs	1	400	500	600	$\mathrm{mV}_{\mathrm{rms}}$
3	AF-output voltage	V_{58FM}	R_L >10k Ω ; no Deemph.	Lab	1	600		mV_{rms}
4	Input voltage for	V_7	V ₅₈ =V _{58 FM} - 3dB	1		33	42	μV_{rms}
	limiter threshold							
5	Total harmonic	THD ₁		1			1.2	%
	distortion							
6	AM-suppression	a_{AM}	m=30 %	1	70	80		dB
7	Signal-to-noise ratio	a _{S/N}		1	72	80		dB
8	AF mute	a_{AF}	V ₅₉ =0	1	10	12	14	dB
<u>Multi</u>	path detector		f ₅₇ =200 kHz					
10	Attack current	I ₁ *)	V_{64AC} =1 V_{pp} , V_{m} =5.0 V	1	600	800	1000	μΑ
11	Recovery current	l ₁ *)	V_{64AC} =0; V_{m} =3.6 V	1	- 6	- 9	-12	μΑ
12	Start voltage	V_{2Def}	V _{57AC} =0V	1	4.4	4.7		٧
13	Detector characteristic	V_2	f_{57} =25kHz; V_{57} =100m V_{pp}	1	V _{2Def-0.14V}	V _{2Def-0.1V} V	2Def-0.07V	V
14	Detector characteristic	V_2	f_{57} =200kHz; V_{57} =100m V_{pp}	1	V _{2Def-1.8V}	V _{2Def} -1.6V	V _{2Def-1.4V}	V

^{*)} Integrator currents are measured between the output pin (- Pole $\,$ of the measurement equipment) and a voltage source V_m (+ Pole)

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AC/DC Characteristics

AC / DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature range. Typical characteristics are the median of the production.

Parameter Symbol Test Test Min Typ Max Units
Conditions Circuit

3.Stereodecoder

Measuring condition:

V₅₃=600mV_{rms}; f=1 kHz; 15kHz LP with 19kHz Notch; see appendix

1	Total harmonic	THD _{47,48} f= 1 kHz	1		0.1	0.3	%
	distortion						
2	Signal to noise ratio	S/N _{47,48} Stereo	1	65	75		dB
3	Channel separation	a _{Sep}	1	28	40		dB
4	AF output voltage	V _{47,48} Stereo	1	310	390	470	$\rm mV_{rms}$
5	Overdrive margin	V _{47,48 max} THD= 1%	1	4	8		dB
6	AF output DC voltage	V _{DC 47,48}	1	2.5	3	3.5	V
7	Difference of output	$\Delta_{ extsf{V47,48}}$	1			2	dB
	voltage levels						
8	Muting depth	A _{47,48} V ₄₄ =0	1	70	75		dB
9	Muting depth	A _{47,48} V ₄₄ =0.7V	1	70	75		dB
10	DC-offset at mute	Δ_{DC} 47,48	1	-100	0	100	mV
11	DC-offset stereo on/off	$\Delta_{ extsf{DC 47,48}}$	1	-100	0	100	mV

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#	Parameter	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
Carri	er and harmonic sunr	oression (re	eferenced to V _{47,48} =390 i	mV)				
1	Pilotsignal (f=19kHz)	α ₁₉	7101011000 10 1 47,48 - 000 1	1	40	45		dB
•	subcarrier	~ 19		•	40	40		uВ
2	(f=38kHz)	α_{38}		1	40	50		dB
3	(f=57kHz)	α ₅₇		1	40	50		dB
Mono	/Stereo control							
	Pilot threshold voltage	<u>ə:</u>						
1	For stereo"on"	V_{PILon}		1		20	30	mV_{rms}
2	For stereo"off"	V _{PILoff}		1	5	14		mV_{rms}
3	Hysteresis		V_{PlLon} / V_{PlLoff}	1		3		dB
	Stereo-indicator outpu	<u>ut</u>						
4	Pilot off	V _{51off}	I ₅₁ =1mA				0.5	V
5	Pilot on	I _{51on}	V ₅₁ =8V				10	μΑ
	external control voltage	ges (active l	<u>ow)</u>					
6	Operational voltage for	or external		1			1	V
	mono control (pin 52)	V_{52thr}						
7	Operational voltage for	or		1			1	V
	AM/FM (pin 43)	V _{43thr}	AM on					
Deem	phasis		Reference frequency = 4	00Hz				
	-		C_{deemph} =10nF; τ_{nom} =75					
8	Minimum FM	A _{min FM}	$V_{49} \ge 3.8V$; $f_m = 5kHz$	1	6.6	7.8	9	dB
9	Maximum FM		$V_{49} = 0V; f_m = 5kHz$	1	13	16	19	dB
10	Minimum AM	A _{min AM}	V ₄₉ ≥ 4.4V; f _m =5kHz	1	6.6	7.8	9	dB
11	Maximum AM	A _{max AM}	$V_{49} = 0V; f_m = 5kHz$	1	11.5	14.5	17.5	dB

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#	Parameter	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
Stere	eo/Mono blend contro	ol:						
1	Channel separation	a _{Sep}	V ₅₀ =3.8V	1	28			dB
2	Channel separation	a _{Sep}	V ₅₀ =3.2V	1			3	dB
Oscill	lator							
3	Max. Osc. frequency	f _{oscmax}	100 % x (f _{max} /456kHz-1)	1	0.7	1.0	2.0	%
4	Min. Osc. frequency	f_{oscmin}	100 % x (f _{min} /456kHz-1)	1	-2.0	-1.0	-0.7	%
5	VCO-gain	$\Delta f/\Delta V_1$		1	-12	-8	-4	kHz/V
6	Oscillator voltage	V_{55DC}		1	2.5	4	5.5	V
7	Oscillator swing	V_{55AC}		1	260	370	470	mV_{rms}
PLL								
8	PD-gain	$\Delta i/\Delta \phi$	$V_{pilot} = 54 \text{ mV}_{rms}$	note 1	6.0	8.2	10.2	μA/rad
Noise	e detector							
9	Input resistance	R ₅₇		Lab	80	99	120	kΩ
10	Input high-pass filter	f _{in57}	-3dB	Lab	80	100	120	kHz
11	Trigger threshold	$V_{57 min}$	$V_{44} = V_{44} (V_{57 \text{ mean}} = 0)$,					
			f ₅₇ =200 kHz	1		30	50	mV_{rms}
12	Trigger threshold	V _{57 dyn}	$V_{44} = V_{44} (V_{57 \text{ mean}} = 50 \text{mV})$	′ _{rms}),				
			f ₅₇ =200 kHz	1	130	170	210	mV_{rms}
13	Maximum	V _{57 maxm}	ean	1				
	noise mean value *		f ₅₇ =200 kHz		65	80	115	mV_{rms}
14	Suppression pulse d	uration		1	34	40	46	μs
15	Input offset current	I _{45,46}		Lab	-50	0	50	nA

^{*)} The trigger threshold is adapted to the input noise. IF max. noise mean value is exceeded, threshold is too high for any trigger of the noise blanker.

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#	Parameter	Symbol	Test	Test	Min	Тур	Max	Units
			Conditions	Circuit				

4.AM Mode

AGC-Amplifier

Measuring condition:

 $f_{iF}\!\!=$ 450 kHz; f_{mod} = 1 kHz; V_{9} = 10mV $_{rms}$, Deemphasis=100 μs

1 2 3 4 5	AGC-range Input sensitivity AGC time seek mode on AGC time seek mode off Integrator Current	0 =	$V_{58} = V_{58AM} \pm 3dB$ $V_{58} = V_{58AM} - 3dB$ $V_{9} = 0; V_{m} = 3V$	1 1 1 1	70 0 2.4 +80	80 30 +100	0.7 5 +120	dB μV _{rms} V V μΑ
6	Integrator Current	I ₁₃ *	$V_9 = 200 \text{mV}_{\text{rms}}$; $V_m = 3 \text{V}$	1	- 80	-100	- 120	μA
7	Integrator Current	I ₁₃ *	V ₉ =0 V _m =3V; V ₃ =0.7 V	1	+520	+650	+780	μΑ
8	Integrator Current	I ₁₃ *	$V_9 = 200 \text{mV}_{\text{rms}}$; $V_m = 3\text{V}$; $V_3 = 0.7 \text{ V}$	1	- 520	-650	- 780	μA
9	Field strength output	V ₆₃	V ₉ =0 mV; seek mode off	1	0	0.3	0.6	V
10		V ₆₃	$V_9 = 100 \mu V$; seek mode off	1	1.4	1.7	2.1	V
11		V ₆₃	V_9 =500 μ V; seek mode off	1	2.4	2.7	3.0	V
12		V_{63}	V ₉ =5 mV; seek mode off	1	3.5	4.1	4.7	V
13		V ₆₃	V ₉ =30 mV; seek mode off	1	4.0	4.6	5.1	V
	odulator							
17	AF output voltage	V_{58AM}	m=0.8	1	360	480	600	mV_{rms}
18	AF output voltage	V_{1AM}	m=0.8; Deemph=100 μs	Lab	305	406	507	mV_{rms}
19	Total harm. distortion	THD ₆₄	m=0.8	1		0.7	2	%
20	(S+N)/N		m=0.8; V ₉ =20 μV	1		30		dB
	(S+N)/N		m=0.8; V ₉ =200 μV	1		50		dB
21	(S+N)/N		$m = 0.8; V_9 = 100 \text{ mV}_{rms}$	1		66		dB
22	AF-linearity	$\Delta_{ m V58}$	V ₉ =100μV/50 mV	1			3	dB
IF - C	ounter							
23 24	IF - counter Output voltage IF-counter	V_4	$R_L=100k\Omega$ $V_3=0.7 V$	1	320	400	480	mV_{rms}
25	output voltage IF-counter	V_4	V ₃ =2.4 V	1			1	V_{DC}
20	Output voltage	V_{4AC}	V ₃ =2.4V	1			1	mV_{rms}

^{*)} Integrator currents are measured between the output pin (- Pole $\,$ of the measurement equipment) and a voltage source V_m (+ Pole)

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#	Parameter	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
	oly voltage ient temperature	V _S =8.5 T _{amb} = - 4	V 40 to +85 °C					
	Current consumption //FM-Receiver	I _{SFM} I _{SAM}	FM mode AM mode	1 1	70 66	100 96	130 124	mA mA
2 3 4 5 6 7 10.7 8 9 10 11 12 13 14 15 16	Frequency range Frequency range Counter output Divided counter output Output impedance Output impedance Frequency MHz IF amplifier DC input voltage Input resistance Output resistance Output resistance Voltage gain Voltage gain Noise figure Reference voltage Output Current	f _{1st LO} f _{1st LO} V ₄₁ V ₄₀ R ₄₀ R ₄₁ f _{1st LO} V ₂₃ R ₂₃ R ₁₈ R ₁₉ A ₂₃₋₁₉ A ₂₃₋₁₉ A ₂₃₋₁₈ F _{AM} F _{FM} V ₃₇ I ₃₇	$\begin{array}{l} Q_{factor\ of\ coil}>\!\!90\\ R_{L41}\!=\!330\Omega\\ R_{L40}\!=\!330\Omega\\ \end{array}$ $\begin{array}{l} V_{tuning}\!=\!\!0V\\ f_{IF1}\!=\!10.7\ MHz\\ \end{array}$ $\begin{array}{l} AM/FM\\ open\ Collector\\ FM,\ R_{19}\!=\!330\Omega\\ AM,\ R_{18}\!=\!330\Omega\\ RG\!=\!330\Omega\\ RG\!=\!330\Omega\\ \end{array}$	1 Lab 1 Lab Lab 1 1 Lab Lab Lab 1	80 50 90 90 0.7 210 tbf 4.3 1.35 100 230 22 6	130 130 1 330 4.7 1.8 330 27 11 6 7 4.8	140 150 1.3 390 2.35 430 32 16	MHz MHz mV _{rms} mV _{rms} kΩ Ω MHz V kΩ kΩ dB dB dB dB dB V mA
AMı	<u>node</u>		f_{IF1} = 10.7 MHz f_{IF2} = 450 kHz f_{33-34} = 1 MHz V_{43} =1V					
2	Interceptpo 3rd order Mixer gain	A _{M1}	Special testcircuit necessary $V_{33,34}$ =80m V_{rms} ; V_{out} = V_{23} (X_F =1k5//5p; a_F =-2dB)	Lab Lab		134 -2		dBμV dB
	Over all gain Max. input voltage Noise figure (10 MHz)	A _{M IF} V ₃₃₋₃₄ F	$V_{33,34}$ =80m V_{rms} ; V_{out} = V_{IF10} . SINAD> 34dB;m=80% $R_{g\ opt}$ =700 Ω	. ₇ 1 1 Lab	-1 1000	5 1400 7	11	dB mV _{pp} dB
6 7 8 9 10 11	Input impedance Input impedance Input impedance Input impedance 1st LO divided by 8 1st LO divided by 10	R ₃₃₋₃₄ C ₃₃₋₃₄ R ₃₃₋₃₄ C ₃₃₋₃₄ V _{24Low} V _{24High}	sym. sym. asym. asym. or open	Lab Lab Lab Lab 1	3.1 1.5 1.5 3.1 0 2.4	4 2 2 4	4.9 2.5 2.5 4.9 0.7 5	kΩ pF kΩ pF V V

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Pres	tage AGC output							
	AGC-voltage AM	V ₂₀	$V_{33,34} = 50 \text{mV}_{rms}$	1	6	7		V
	AGC-voltage AM	V ₂₀	$V_{33,34} = 200 \text{mV}_{rms}$	1	0		0.7	V
	AGC-voltage FM	V ₃₂	V _{33,34} =50mV _{rms}	1	0		0.5	V
13	AGC-current FM	l ₂₁	$V_{33,34} = 50 \text{mV}_{rms}$	1	0		0.5	mΑ
14	Integrator Current	l ₃₁ *	$V_{33,34} = 50 \text{mV}_{rms} \text{ V}_{m} = 3 \text{V}$	1	-28	-38	- 53	μΑ
15	Integrator Current	l ₃₁ *	$V_{33,34} = 200 \text{mV}_{\text{rms}} \text{V}_{\text{m}} = 3 \text{V}$	1	+30	+40	+55	μΑ
2 nd Mixe	AM IF section							
	Max. Mixer gain	A _{M2}	V ₁₇ =1mV; V _{out} =V _{IF450} ₇ =10.7 MHz; f ₁₄ =10.25 MHz	1	15	20	25	dB
2	Mixer AGC-range	ΔΑ	$\Delta A = A_{V17=1mV} - A_{V17=100 mV}$	1	15	20	25	dB
	Mixer gain seek mode		$V_{17}=1$ mV; $V_{3}=0.7$ V	1	15	20	25	dB
	Noise figure	F	7 3	Lab		10		dB
	Integrator Current	l ₄₂ *	$V_{17}=0 \ V_{m}=3V$	1	+70	+150	+250	μΑ
6	Integrator Current	l ₄₂ *	$V_{17}=100 \text{mV}_{\text{rms}}$ $V_{\text{m}}=3 \text{V}$	1	-180	-270	-400	μΑ
2nd								
	Operational frequency			1	9.25	10.25	11.25	MHz
	External force voltage	V ₁₄	Rg=600Ω;Ck= 100pF	1	30			mV_{rms}
	Input Imp. Crystal Osc			Lab	-500	-600	-400	Ω
	Crystal Resistance	R_{C1}	P _{TOTC} =50μW; Fundamental	Lab	00		100	Ω
9	Spurious Harm. Cryst.	a_{SP}	P _{TOTC} =50μW; F<30 MHz	Lab	-20			dB
<u>FM r</u>	node		f _{IF} =10.7 MHz f ₃₅₋₃₆ =100 MHz V ₄₃ =open					
Mixe	r 1		v ₄₃ –open					
	Interceptpoint	I _{P3}		Lab		125		dB μV
•	3rd order	'P3	special testcircuit necessary	Lub		120		αΒ μν
2	Noise figure (10 MHz)	F	$R_{g \text{ opt}} = 500\Omega$	Lab		6		dB
	Mixer gain	A _{M1}	$V_{35-36}^{g \text{ opt}} = 10 \text{mV}_{rms}; V_{out} = V_{23}$ (R _F =330 Ω ; a _F =-4dB)	Lab		9		dB
4	Over all gain	A_{MIF}	$V_{35,36}=10 \text{mV}_{\text{rms}}$; $V_{\text{out}}=V_{\text{IF}10}$	₇ 1	25	32	39	dB
	Input impedance	R ₃₅₋₃₆	sym.	., Lab	3.1	4	4.9	$k\Omega$
6	Input impedance	C_{35-36}	sym.	Lab	1.5	2	2.5	pF
7	Input impedance	R ₃₅₋₃₆	asym.	Lab	1.5	2	2.5	$k\Omega$
8	Input impedance	C_{35-36}	asym.	Lab	3.1	4	4.9	pF
	tage AGC output							
	AGC voltage FM	V_{32}	$V_{35,36}$ =0m V_{rms}	1	5.2	6.4	7.7	V
	AGC voltage FM	V_{32}	$V_{35,36} = 50 \text{mV}_{\text{rms}}$	1	0		0.2	V
	AGC current FM	l ₂₁	$V_{35,36} = 0 \text{ mV}_{rms}$	1	8.5	12	15	mA
	AGC current FM	l ₂₁	$V_{35,36} = 50 \text{mV}_{rms}$	1	0		0.2	mA
	AGC voltage AM	V ₂₈	V _{35,36} =0	1	0	05	1	V ^
	Integrator Current	l ₃₂ *	$V_{35}=0$ $V_{m}=4.8V$	1	-10 - 40	-25 -60	-50	μA Λ
	Integrator Current	1 ₃₂ *	V ₃₅ =100mV _{rms} V _m =4.8V	1	+40	+60	+85	μΑ
	grator currents are measured betv d a voltage source V _m (+ Pole)	veen me outp	out pin (- Pole of the measurement equipm	ieill)				

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			Conditions	Circuit				

2.FM Demodulator

Measuring condition:

 f_{ilF} =10.7 MHz; Δf = \pm 75 kHz; f_{mod} = 1 kHz; V_{7} =10 m V_{rms}

V₄₄=open; Deemphasis= 100 μs

1	Field strength output	V ₆₃						
	-dynamic range	see Dia	gram D1	1	63	75		dB
	-nonlinearity	see Dia	gram D2	1		±1		dB
	-temperature drift	see Dia	gram D3	1			±3	dB
	-load capacitance						50	pF
	-load resistance				1			$k\Omega$
		V ₆₃	$V_7 = 200 \text{mV}_{\text{rms}}$	1	4	4.6	5.2	V
		V ₆₃	$V_7=1 \text{mV}_{\text{rms}}$	1	1.4	1.9	2.4	V
		V ₆₃	V ₇ =0mV _{rms}	1	0		1.5	V
2	AF-output voltage	V_{58FM}	R_L >10kΩ; Deemph.=100 μs	1	350	500	650	mV_{rms}
3	AF-output voltage	V_{58FM}	R_L >10k Ω ; no Deemph.	Lab)	600		mV_{rms}
4	Input voltage for	V_7	V ₅₈ =V _{58 FM} - 3dB	1		33	45	μV_{rms}
	limiter threshold							
5	Total harmonic	THD ₁		1			1.2	%
	distortion							
6	AM-suppression	a_{AM}	m=30 %	1	70	80		dB
7	Signal-to-noise ratio	a _{S/N}		1	72	80		dB
8	AF mute	a_{AF}	V ₅₉ =0	1	9	12	15	dB
Multi	path detector		f ₅₇ =200 kHz					
10	Attack current	l ₁ *)	V_{64AC} =1 V_{pp} , V_{m} =5.0 V	1	500	800	1100	μΑ
11	Recovery current	l ₁ *)	V_{64AC} =0; V_{m} =3.6 V	1	-3	-9	-14	μΑ
12	Start voltage	V_{2Def}	V _{57AC} =0V	1	4.3	4.7		V
13	Detector characteristic	V_2	f_{57} =25kHz; V_{57} =100m V_{pp}	1	V _{2Def-0.15V} \	/ _{2Def-0.1V} V	2Def -0.05V	V
14	Detector characteristic	V_2	f ₅₇ =200kHz; V ₅₇ =100mV _{pp}	1	V _{2Def} -2.0V \	/ _{2Def -1.6V} \	√ _{2Def} -1.2V	V

^{*)} Integrator currents are measured between the output pin (- Pole $\,$ of the measurement equipment) and a voltage source V_m (+ Pole)

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Conditions Circuit

3.Stereodecoder

Measuring condition:

V₅₃=600mV_{rms}; f=1 kHz; 15kHz LP with 19kHz Notch; see appendix

1	Total harmonic	THD _{47,48} f= 1 kHz	1		0.1	0.5	%
	distortion						
2	Signal to noise ratio	S/N _{47,48} Stereo	1	65	75		dB
3	Channel separation	a _{Sep}	1	26	40		dB
4	AF output voltage	V _{47,48} Stereo	1	300	390	500	${\rm mV}_{\rm rms}$
5	Overdrive margin	$V_{47,48 \text{ max}}$ THD= 1%1	3	8		dB	
6	AF output DC voltage	V _{DC 47,48}	1	2.3	3	3.7	V
7	Difference of output	$\Delta V_{47,48}$	1			2	dB
	voltage levels						
8	Muting depth	A _{47,48} V ₄₄ =0	1	70	75		dB
9	Muting depth	A _{47,48} V ₄₄ =0.7V	1	70	75		dB
10	DC-offset at mute	$\Delta_{ extsf{DC 47,48}}$	1	-100	0	100	mV
11	DC-offset stereo on/off	$\Delta_{DC\ 47,48}$	1	-100	0	100	mV

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#	Parameter S	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
Carrie	er and harmonic supp	ression (re	eferenced to V _{47,48} =390	mV _{rms})				
1	Pilotsignal (f=19kHz) subcarrier	α_{19}		1	40	45		dB
2	(f=38kHz)	α_{38}		1	40	50		dB
3	(f=57kHz)	α_{57}		1	40	50		dB
Mono	/Stereo control							
	Pilot threshold voltage	<u>e:</u>						
1	For stereo"on"	V_{PILon}		1		20	40	mV_{rms}
2	For stereo"off"	V_{PILoff}		1	2	15		mV_{rms}
3	Hysteresis		V _{PILon} / V _{PILoff}	1		3		dB
	Stereo-indicator outpu	<u>ut</u>						
4	Pilot off	V_{51off}	I ₅₁ =1mA				0.5	V
5	Pilot on	l _{51on}	V ₅₁ =8V				10	μΑ
	external control voltage	ges (active l	ow)					
6	Operational voltage for	or external		1			1	V
	mono control (pin 52)	V _{52 thr}						
7	Operational voltage for	or		1			1	V
	AM/FM (pin 43)	V _{43thr}	AM on					
Deem	phasis		Reference frequency = 4	100Hz				
			C_{deemph} =10nF; τ_{nom} =75	μs				
8	Minimum FM	$A_{min\;FM}$	$V_{49} \ge 3.8V; f_m = 5kHz$	1	5.5	7.2	9.4	dB
9	Maximum FM	$A_{\text{max FM}}$	$V_{49} = 0V; f_m = 5kHz$	1	11.5	14.5	19	dB
10	Minimum AM	$A_{min\ AM}$	$V_{49} \ge 4.4V$; $f_m = 5kHz$	1	5.5	7.2	9.4	dB
11	Maximum AM	A _{max AM}	$V_{49} = 0V; f_m = 5kHz$	1	10	14.5	19	dB

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#	Parameter	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
			Conditions	Onodit				
Stere	eo/Mono blend contro	ol:						
1	Channel separation	a_Sep	$V_{50} = 3.8V$	1	26			dB
2	Channel separation	a_{Sep}	V ₅₀ =3.2V	1			5	dB
Osci	llator							
3	Max. Osc. frequency	/ f _{oscmax}	100 % x (f _{max} /456kHz-1)	1	0.7	1.0	2.0	%
4	Min. Osc. frequency		100 % x (f _{min} /456kHz-1)	1	-2.0	-1.0	-0.7	%
5	VCO-gain	Δ f/ Δ V $_{54}$		1	-13	-8	-3	kHz/V
6	Oscillator voltage	V _{55 DC}		1	2	4	6	V
7	Oscillator swing	V _{55 AC}		1	240	370	490	${\rm mV}_{\rm rms}$
PLL								
8	PD-gain	Δί/Δφ	$V_{pilot} = 54 \text{ mV}_{rms}$	note 1	5	8.2	11.2	μA/rad
Nois	e detector							
9	Input resistance	R ₅₇		Lab	70	99	130	$k\Omega$
10	Input high-pass filter	f _{in57}	-3dB	Lab	70	100	130	kHz
11	Trigger threshold	$V_{57 min}$	$V_{44} = V_{44} (V_{57 \text{ mean}} = 0)$,					
			f ₅₇ =200 kHz	1		30	60	mV_{rms}
12	Trigger threshold	V _{57 dyn}	V ₄₄ =V ₄₄ (V _{57 mean} =50m\	/ _{rms}),				
			f ₅₇ =200 kHz	1	110	170	260	mV_{rms}
13	Maximum	V _{57 maxm}	ean	1				
	noise mean value *		f ₅₇ =200 kHz		60	80	120	mV_{rms}
14	Suppression pulse d	luration		1	30	40	50	μs
15	Input offset current	I _{45,46}		Lab	-50	0	50	nA

^{*)} The trigger threshold is adapted to the input noise. IF max. noise mean value is exceeded, threshold is too high for any trigger of the noise blanker.

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IC-SPECIFICATION

TUA 4300 G

AC/DC Characteristics

AC / DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature range. Typical characteristics are the median of the production.

#	Parameter	Symbol	Test	Test	Min	Тур	Max	Units
			Conditions	Circuit				

4.AM Mode

AGC-Amplifier

Measuring condition:

 $f_{iF}\!\!=$ 450 kHz; f_{mod} = 1 kHz; V_{9} = 10mV $_{rms}$, Deemphasis=100 μs

1 2	AGC-range Input sensitivity	ΔA V $_{9}$	V ₅₈ =V _{58AM} ±3dB	1 1	64	80 30		dB
3	AGC time seek mode on		$V_{58}=V_{58AM}$ -3dB	1	0	30	0.7	μV _{rms} V
4		0 =		1	2.4		5	V
5	Integrator Current	vзн I ₁₃ *	$V_9=0; V_m=3V$	1	+70	+100	+130	μA
6	Integrator Current	I ₁₃ *	$V_9 = 200 \text{mV}_{\text{rms}}$; $V_m = 3 \text{V}$	1	- 70	-100	-130	μΑ
7	Integrator Current	I ₁₃ *	$V_9 = 0$ $V_m = 3V$; $V_3 = 0.7$ V	1	+450	+650	+845	μΑ
8	Integrator Current	I ₁₃ *	V ₉ =200mV _{rms} ; V _m =3V; V ₃ =0,7 V	1	- 450	-650	-845	μΑ
9	Field strength output	V ₆₃	V ₉ =0 mV; seek mode off	1	0	0.3	0.8	V
10		V ₆₃	V ₉ =100μV; seek mode off	1	1.2	1.7	2.3	V
11		V ₆₃	$V_9=500 \mu V$; seek mode off	1	2.2	2.7	3.2	V
12		V ₆₃	V ₉ =5 mV; seek mode off	1	3.3	4.1	4.9	V
13		V ₆₃	V ₉ =30 mV; seek mode off	1	3.8	4.6	5.4	V
Demo	odulator							
17	AF output voltage	V_{58AM}	m=0.8	1	335	480	650	mV_{rms}
18	AF output voltage	V_{1AM}	m=0.8; Deemph=100 μs	Lab	283	406	550	mV_{rms}
19	Total harm. distortion	THD ₆₄	m=0.8	1		0.7	2.5	%
20	(S+N)/N		m=0.8; V ₉ =20μV	1	20	30		dB
	(S+N)/N		m=0.8; V ₉ =200 μV	1	40	50		dB
21	(S+N)/N		$m = 0.8; V_9 = 100 \text{mV}_{rms}$	1	56	66		dB
22	AF-linearity	Δ_{V58}	$V_9 = 100 \mu V / 50 \text{ mV}$	1			3	dB
IF - C	ounter							
23	IF - counter	V_4	$R_L=100k\Omega$	1	285	400	580	mV_{rms}
	Output voltage		V ₃ =0.7 V					
24	IF-counter							
	output voltage	V_4	V ₃ =2.4 V	1			1	V_{DC}
25	IF-counter							-
	Output voltage	V_{4AC}	V ₃ =2.4V	1			2	${\rm mV}_{\rm rms}$

^{*)} Integrator currents are measured between the output pin (- Pole $\,$ of the measurement equipment) and a voltage source V_m (+ Pole)

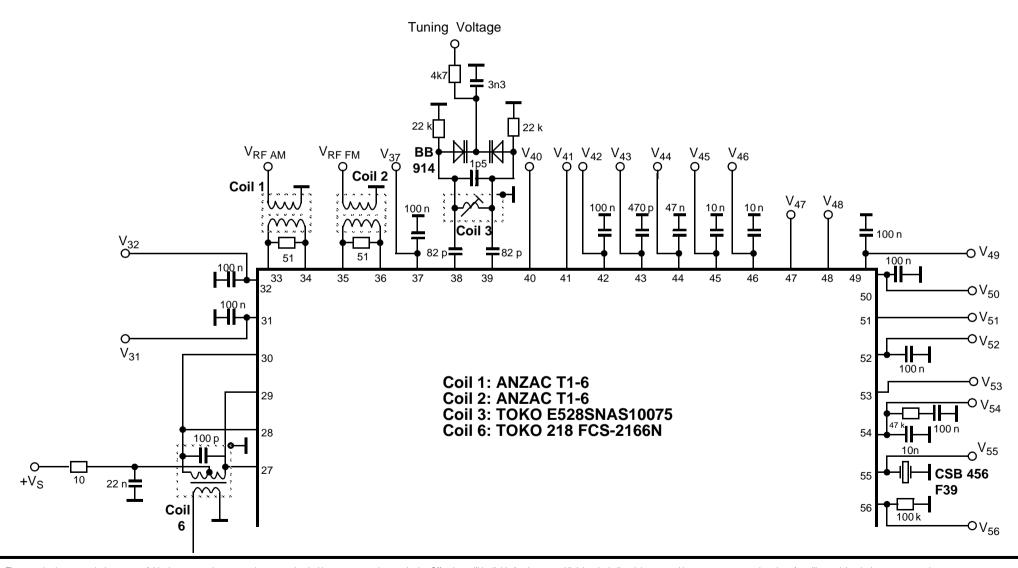
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Test Circuit

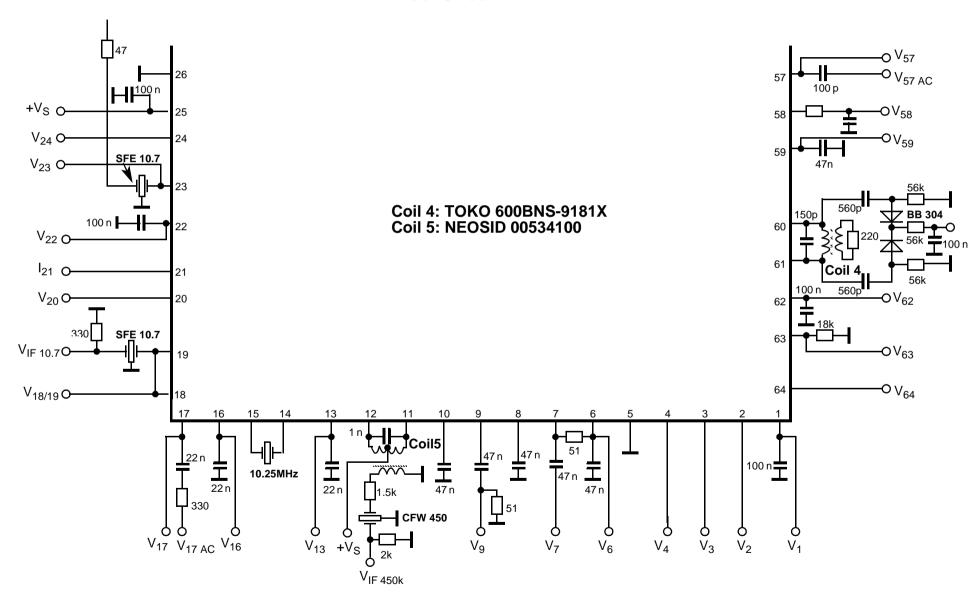


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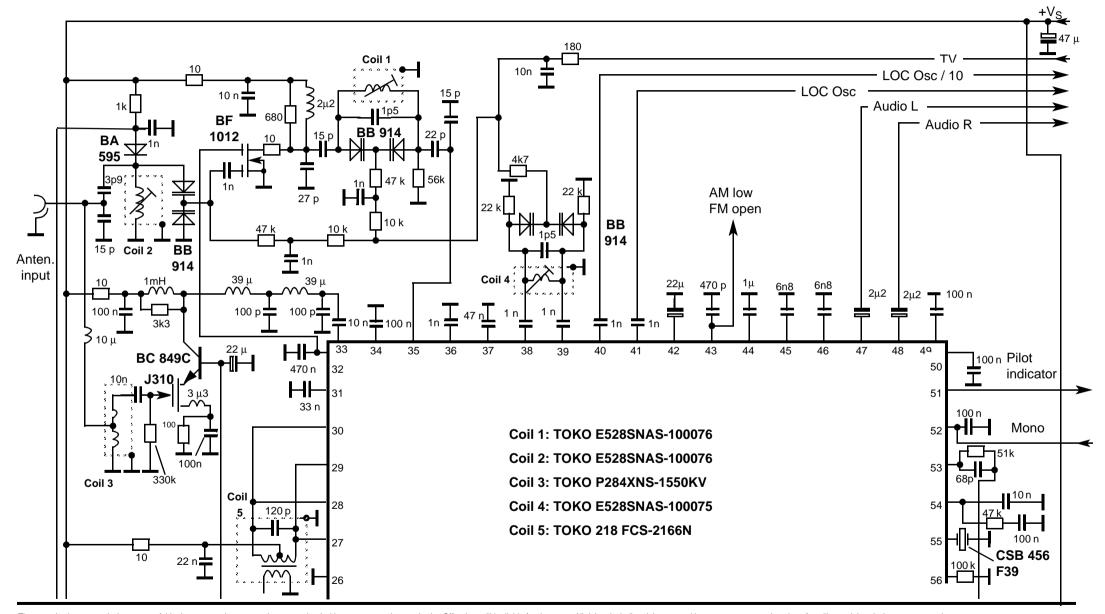
TUA 4300 G

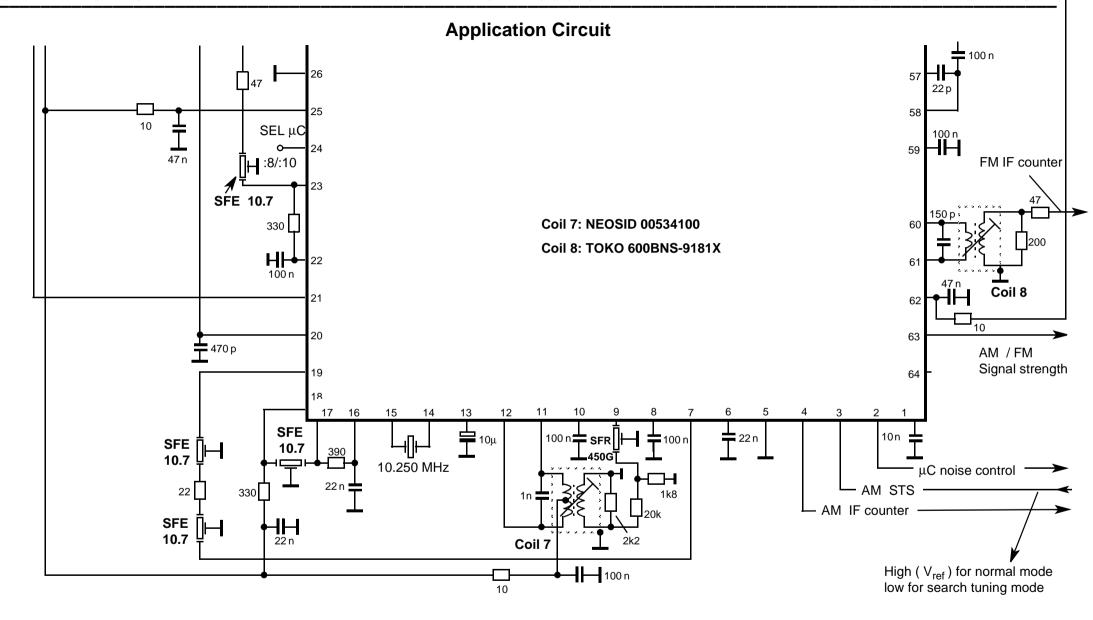
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Test Circuit



Application Circuit



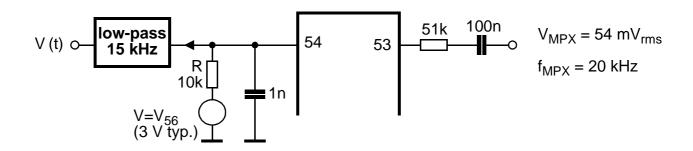


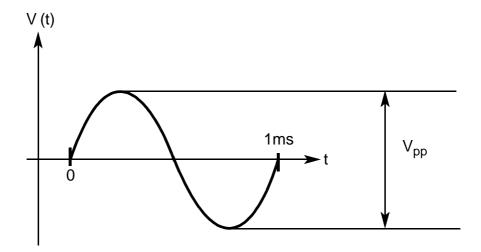
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TUA 4300 G

Diagrams

Note 1: Definition of Phase Detector Gain





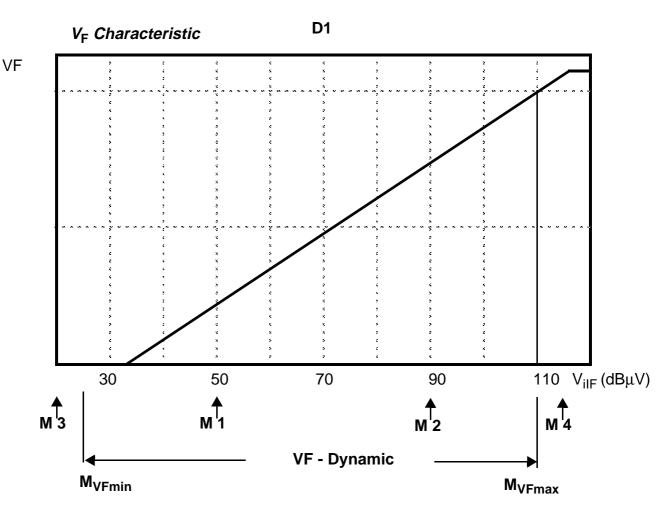
Phase Detector Gain PDG =
$$\frac{V_{pp}}{2R}$$
 / rad

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IC-SPECIFICATION

TUA 4300 G

Diagrams



V_F - Dynamic: The dynamic range of VF voltage is determined by the test points M1 through M4 as follows:

M1: test point (at V_{iIF} = 50 dB μ V) supplies V_F (M1) M2: test point (at V_{iIF} = 90 dB μ V) supplies V_F (M2) M3: test point (at V_{iIF} = 20 dB μ V) supplies V_F (M3) M4: test point (at V_{iIF} =120 dB μ V) supplies V_F (M4)

Hence follows:

$$M_{VFmax}$$
:= 90 dB μ V + $\frac{V_F (M4) - V_F (M2)}{V_F (M2) - V_F (M1)} \times 40 dB$

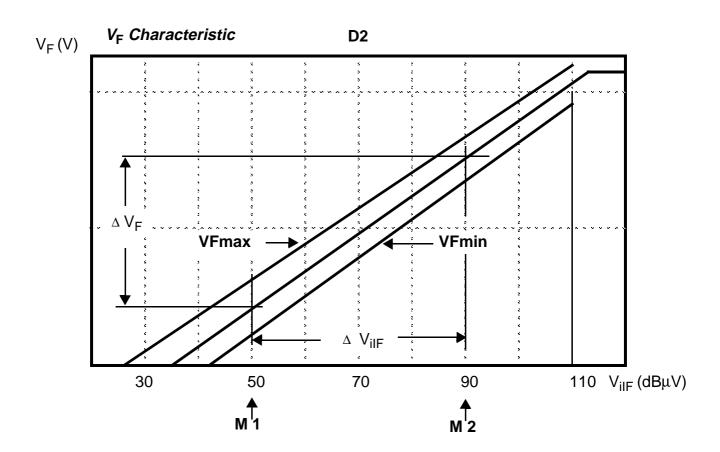
$$M_{VFmin} := 50 \text{ dB}\mu\text{V} - \frac{V_F (M1) - V_F (M3)}{V_F (M2) - V_F (M1)} \times 40 \text{ dB}$$

<u>VF - Dynamic</u> = M_{VFmax} - M_{VFmin}

IC-SPECIFICATION

TUA 4300 G

Diagrams



Test points to determine VF linearity

VF - Linearity: is determined at 25 °C

Slope :
$$m = \frac{V_F (M2) - V_F (M1)}{40 \text{ dB}}$$

The tolerance range of the VF - linearity is determined by two parallel lines:

$$V_{Fmax} = V_F (M1) + m (M + 60 dB + 1dB)$$

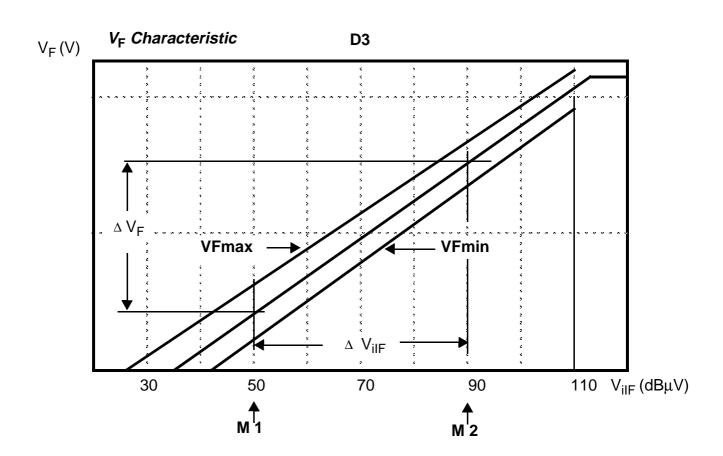
$$V_{Fmin} = V_F (M1) + m (M + 60 dB - 1dB)$$

The V_F values within the V_F dynamic range $(M_{VFmin}{\le}M{\le}M_{VFmax})$ must be inside the predetermined tolerance range:

$$V_{Fmin} \leq V_{F}$$
 (M) $\leq V_{Fmax}$

TUA 4300 G

Diagrams



Test points to determine V_F temperature drift

V_F -Temperatur - Drift : It is determined within -40 bis +85 °C

Slope :
$$m = \frac{V_{F (M2)} - V_{F (M1)}}{40 \text{ dB}}$$
 (at 25 °C)

The tolerance range of the V_{F} temperature drift is determined by two parallel lines:

$$V_{Fmax} = V_{F} (M1) + m (M + 60 dB + 3dB)$$

$$V_{Fmin} = V_F (M1) + m (M + 60 dB - 3dB)$$

The V_F values for temperatures between -40 to +85 °C within the V_F dynamic range ($M_{VFmin} \le VF \le M_{VFmax}$) must be inside the predetermined tolerance field:

VFmin≤ VF (M) ≤ VFmax

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IC-SPECIFICATION

TUA 4300 G

Appendix

AC / DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature range. Typical characteristics are the median of the production.

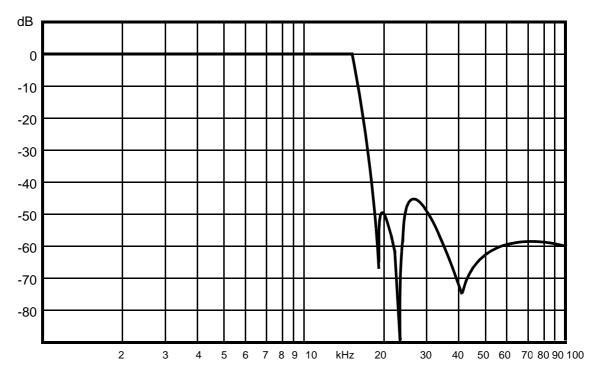
Parameter Symbol Test Test Min Typ Max Units
Conditions Circuit

AC / DC Characteristics

Intermodulation behaviour Stereodecoder section Referenced to $V_{47,48}$ =390 mV_{rms}

1 2	f _{mod} = 10 kHz f _{mod} = 13 kHz	$\begin{array}{c}\alpha_2\\\alpha_3\end{array}$	91% Mono,9%Pilot f_s =1 kHz f_s =2x10kHz-19kHz f_s =3x13kHz-38kHz	Lab Lab	60 70	dB dB
0	(57)))		91% Mono,9%Pilot f _m =1 kHz 5% Traffic Radio Carrier (f=57kHz;fm=23Hz;m=60%)		70	ID.
3	f=57 kHz	α57	fs=1kHz ± 23 Hz	Lab	70	dB

Low pass filter with 19 kHz Notch



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